KJ011N06LFH

N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ☑ Advanced trench cell design
- ☑ Fast switching speed
- ☑ Low thermal impedance
- ☑ 100% avalanche tested

1.2 Applications

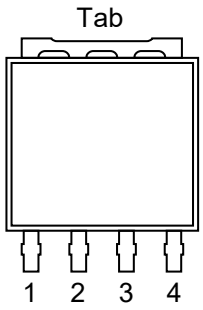
- ☑ DC/DC converter
- ☑ Motor drives
- ☑ Power switch

1.3 Quick reference

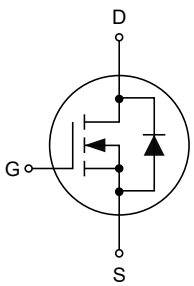
- ☑ BV ≧ 60 V
- ☑ P_{tot} ≦ 156 W
- ☑ I_D ≦ 307 A
- ☑ $R_{DS(ON)}$ ≦ 1.0 mΩ @V_{GS} = 10 V

2. Pin Description

Pin	Description
1,2,3	Source
4	Gate
Tab	Drain



Top View
LFPAK 5×6



3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	Drain-Source Voltage	T_C=25℃	60	-	V
V_{GS}	Gate-Source Voltage	T_C=25℃	-	±20	V
I_D	Continuous Drain Current	T_C=25℃, V_{GS}=10 V [1]	-	307	A
		T_C=100℃, V_{GS}=10 V	-	194	A
I_{DM}	Pulsed Drain Current [2]	T_C=25℃, V_{GS}=10 V	-	1228	A
P_D	Power Dissipation	T_C=25℃	-	156	W
		T_A=25℃ [3]	-	3.5	W
T_J, T_{stg}	Operating Junction and Storage Temperature Range		-55	150	℃
E_{AS}	Single Pulsed Avalanche Energy	V_{DD}=30 V, L=0.3 mH	-	960	mJ
$R_{\theta JA}$	Thermal Resistance-Junction to Ambient		-	40	℃/W
$R_{\theta JC}$	Thermal Resistance-Junction to Case		-	0.8	

Notes:
1. Package limited.
2. Pulse width limited by maximum junction temperature.
3. $R_{\theta JA}$ is determined with the device mounted on a 1 in^2 pad 2 oz copper pad on a 1.5"x1.5" board of FR-4 material.

4. Marking Information

Product Name	Marking
KJ011N06LFH	**KJ011N06LFH XXXXXX-X**

5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity(pcs)
KJ011N06LFH	**LFPAK 5×6**	**13"**	**12 mm**	**5000**

Note: KUAIJIEXIN defines “Green” as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC/JEDEC J-STD-020C)

6. Electrical Characteristics (T_J=25℃ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS}=0 V, I_{DS}=250 μA	60	-	-	V
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS}=V_{GS}, I_{DS}=250 μA	2	-	4	V
I_{DSS}	Drain Leakage Current	V_{DS}=60 V, V_{GS}=0 V	-	-	1	μA
I_{GSS}	Gate Leakage Current	V_{GS}=0 V, V_{GS}=±20 V	-	-	±100	nA
$R_{DS(ON)}$	On-State Resistance [a]	V_{GS}=10 V, I_{DS}=20 A	-	0.85	1.0	mΩ
g_{FS}	Forward Transconductance [b]	V_{GS}=5 V, I_{DS}=20 A	-	75	-	S
R_g	Gate Resistance	Frequency=1 MHz	-	2	-	Ω
Diode Characteristics						
V_{SD}	Diode Forward Voltage [a]	I_{SD}=20 A, V_{GS}=0 V	-	0.7	1.2	V
t_{rr}	Reverse Recovery Time	V_{DS}=30 V, I_{DS}=20 A, dI_{SD}/dt=100 A/μs	-	90	-	ns
Q_{rr}	Reverse Recovery Charge		-	190	-	nC
Dynamic Characteristics [b]						
C_{iss}	Input Capacitance	V_{GS}=0 V, V_{DS}=30 V, Frequency=1 MHz	-	7450	-	pF
C_{oss}	Output Capacitance		-	3400	-	
C_{rss}	Reverse Transfer Capacitance		-	175	-	
$t_{d(on)}$	Turn-on Delay Time	V_{DS}=30 V, V_{GEN}=10 V, R_G=3 Ω, I_{DS}=20 A	-	12	-	ns
t_r	Turn-on Rise Time		-	30	-	
$t_{d(off)}$	Turn-off Delay Time		-	90	-	
t_f	Turn-off Fall Time		-	40	-	
Gate Charge Characteristics [b]						
Q_g	Total Gate Charge	V_{DS}=30 V, V_{GS}=10 V, I_{DS}=20 A	-	96	-	nC
Q_{gs}	Gate-Source Charge		-	32	-	
Q_{gd}	Gate-Drain Charge		-	30	-	

Notes:

a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.

b. Guaranteed by design, not subject to production testing.

7. Typical Characteristics

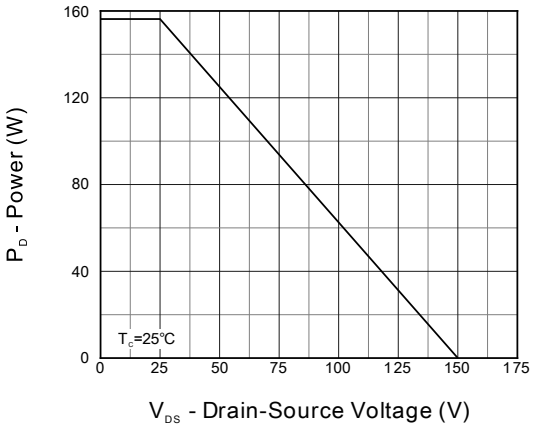


Figure 1. Output Characteristics

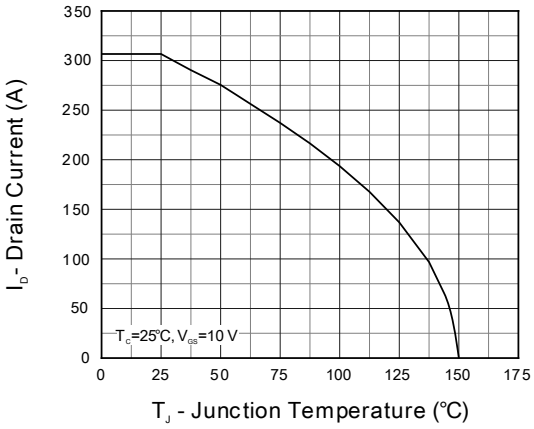


Figure 2. Current Capability

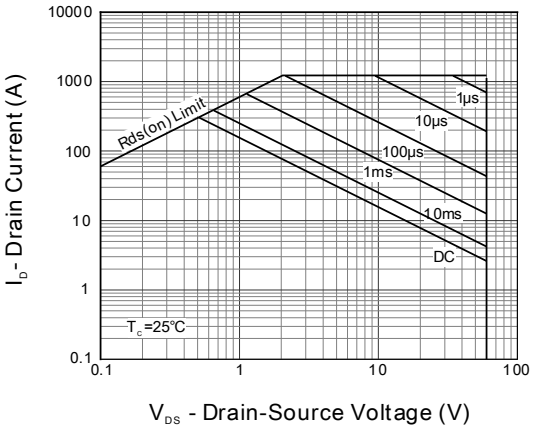


Figure 3. Safe Operation Area

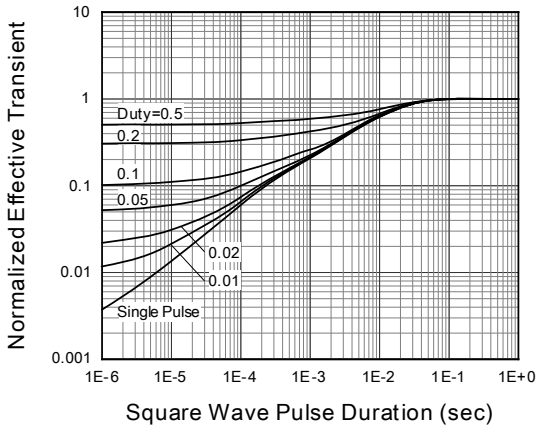


Figure 4. Transient Thermal Impedance

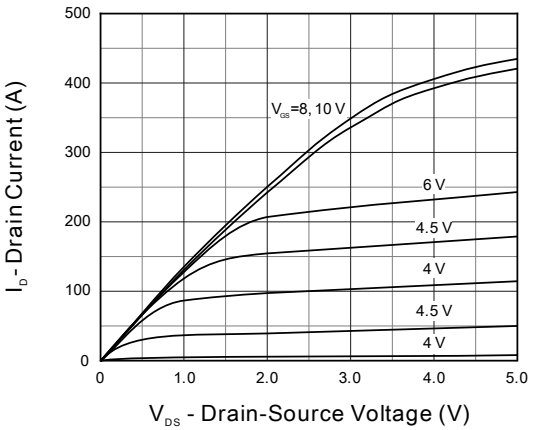


Figure 5. Output Characteristics

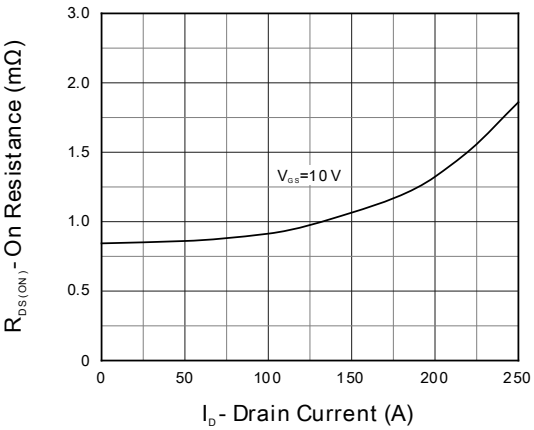


Figure 6. On Resistance

7. Typical Characteristics (cont.)

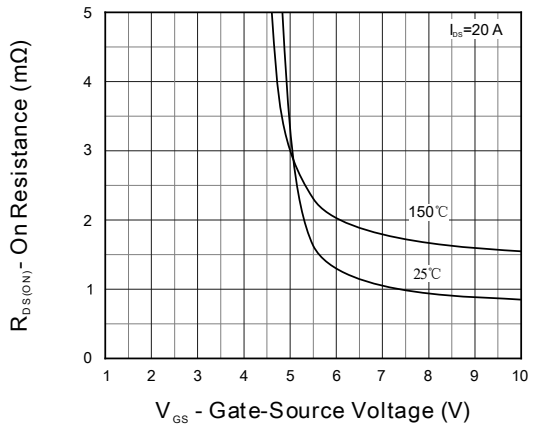


Figure 7. Transfer Characteristics

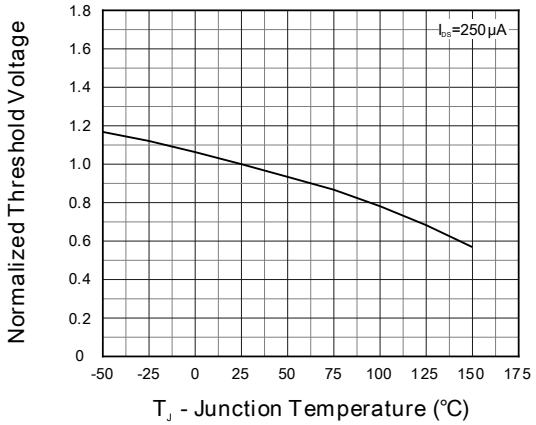


Figure 8. Normalized Threshold Voltage

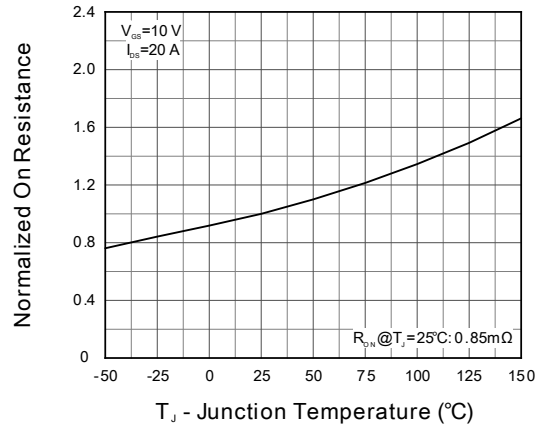


Figure 9. Normalized On Resistance

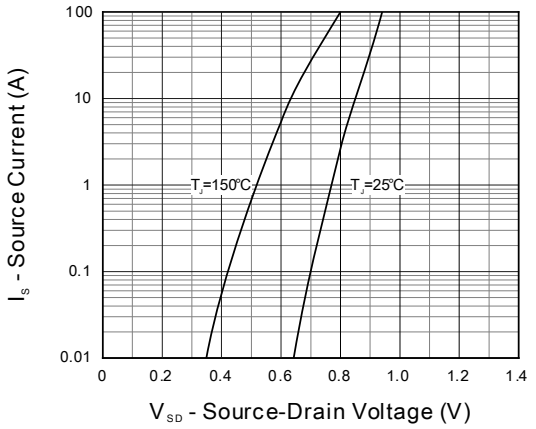


Figure 10. Diode Forward Current

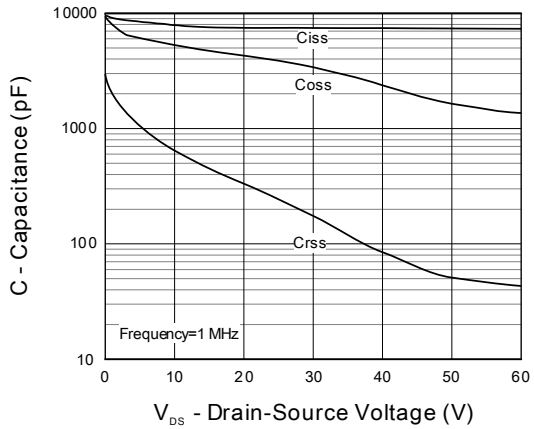


Figure 11. Capacitance

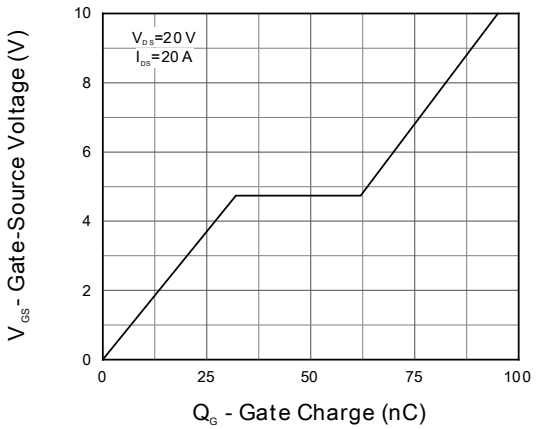
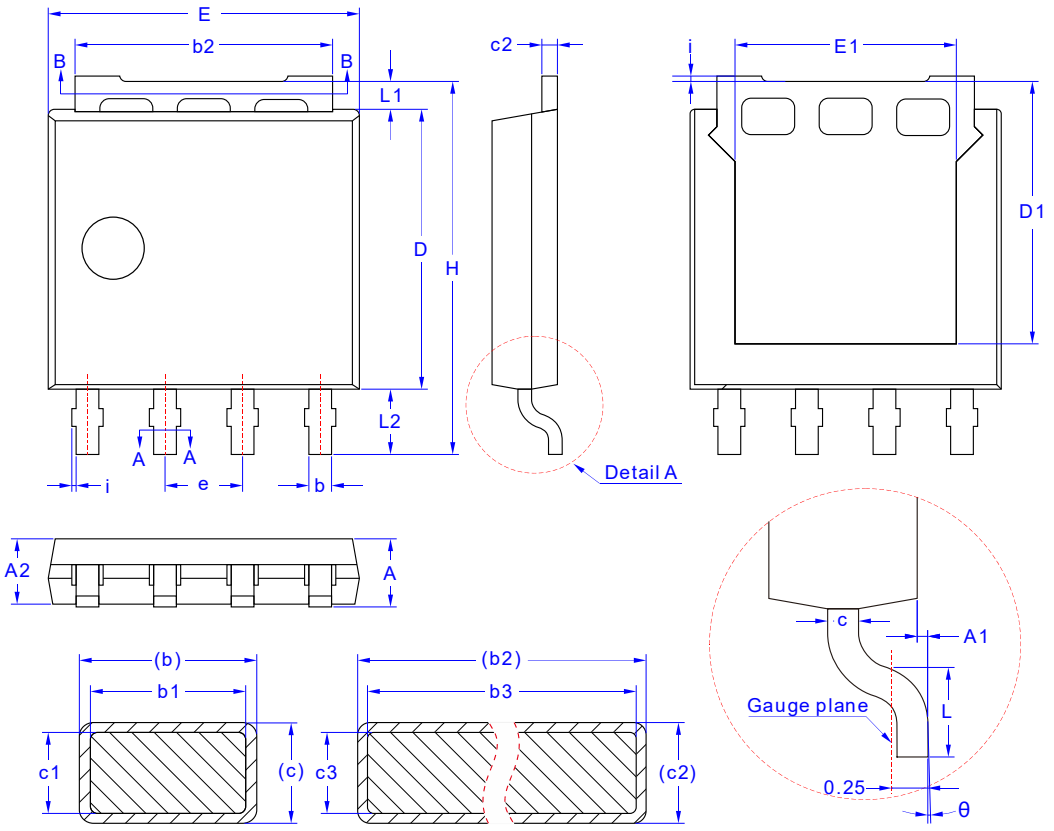


Figure 12. Gate Charge

8. Package Dimensions

LFPAK 5×6 Package



Symbol	Dimensions in Millimeters	
	MIN	MAX
A	1.00	1.30
A1	0	0.15
A2	0.98	1.12
b	0.35	0.50
b1	0.32	0.46
b2	4.02	4.41
b3	4.00	4.37
c	0.19	0.25
c1	0.17	0.23
c2	0.24	0.30
c3	0.22	0.28

Symbol	Dimensions in Millimeters	
	MIN	MAX
D	4.45	4.70
D1	-	4.45
E	4.95	5.30
E1	3.50	3.70
e	1.27 BSC	
H	5.95	6.25
i	-	0.25
L	0.40	0.85
L1	0.27	0.57
L2	0.80	1.30
θ	0°	8°